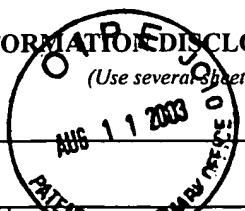


FORM PTO-1449
(REV.7-80)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.
500996.01APPLICATION NO.
09/965,240INFORMATION DISCLOSURE STATEMENT
(Use several sheets if necessary)APPLICANT(S)
Randhir P.S. Thakur et al.FILING DATE
September 26, 2001GROUP ART UNIT
2825

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
VY	AA 5,639,684	06/17/97	Kwok	437	60	—
VY	AB 5,866,938	02/02/99	Takagi et al.	257	530	—
VY	AC 6,458,645 B2	10/01/02	DeBoer et al.	438	240	—
VY	AD 6,515,343 B1	02/04/03	Shroff et al.	257	530	—
—	AE					
	AF					
	AG					
	AH					
	AI					
	AJ					

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
—	AK						
	AL						
	AM						
	AN						
	AO						

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

VY	AP	Kim, J. et al., "High Performance Antifuse with Planar Double Dielectrics on Si _{1-x} Gex Pad for Field Programmable Gate Array Applications", IEEE Electronic Letters, Vol. 32, No. 24, pp. 2276-2277, November 21, 1996.
—	AQ	
	AR	

EXAMINER 11/11/03 V. Yeasir Voi DATE CONSIDERED

* EXAMINER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).